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ARTICLE TYPE

Cite this: DOI: 00.0000/xxxxxxxxx

Supplemental Material for Crystallization of Highly Supercooled Glass-forming Alloys Induced by Anomalous Surface Wetting[†]

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Received Date Accepted Date

DOI:00.0000/xxxxxxxxxx

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1 Computational Methods

1.1 The mean first-passage time method

The mean first-passage time (MFPT) $\tau(x)$ is defined as the average elapsed time that a system reaches the state *x* from its initial state x_0 for the first time. For a activated process, $\tau(x)$ shows a sigmoidal shape. The dynamics of many activated processes can be described in terms of the Fokker-Planck¹

$$\frac{\partial P(x,t)}{\partial t} = \frac{\partial}{\partial x} [D(x)e^{-\beta\Delta G(x)}\frac{\partial}{\partial x}(P(x,t)e^{\beta\Delta G(x)})] = -\frac{\partial J(x,t)}{\partial t},\tag{1}$$

where P(x,t) is the probability density for the state *x* at time *t*. D(x) is the generalized diffusion coefficient, J(x,t) is the state current, $\Delta G(x)$ is the free energy difference and $\beta = 1/k_B T$. The MFPT for an activated process described in Eq. 1 is then given by

$$\tau(x) = \int_{x_0}^x \frac{1}{D(y)} dy exp[\beta \Delta G(y)] \int_a^y dz exp[-\beta \Delta G(z)],$$
(2)

We use the embryo size, n, to identify the thermodynamic state during nucleation. Eq. 2 can be fitted by the following expression²,

$$\tau(n) = \frac{1}{2JV} [1 + erf((n - n^*)c)],$$
(3)

where n^* is the critical size of the nucleus, *J* is the nucleation rate, erf(x) is the error function, and $c = \sqrt{|\Delta G''(n^*)|/2k_BT}$. From the fit of $\tau(n)$, *J* and n^* are obtained accordingly.

If the system reaches the steady state, ie $\partial Pst(x)/\partial t = 0$, Eq.1 can be rewritten as,

$$\frac{\partial(\beta\Delta G(x))}{\partial x} = -\frac{\partial\ln P_{st}(x)}{\partial x} - \frac{J}{D(x)P_{st}(x)},\tag{4}$$

upon integration yields

$$\beta \Delta G(x) = -\ln P_{st}(x) - J \int \frac{dx'}{D(x')P_{st}(x')} + C,$$
(5)

The free energy barrier is then given by 3,4

$$\beta \Delta G(x) = \ln[B(x)] - \int_{a'}^{x} \frac{dx'}{B(x')} + C,$$
(6)

where

$$B(x) = \frac{1}{P_{st}(x)} \left[\int_0^x P_{st}(x') dx' - JV\tau(x) \right].$$
(7)

Using the knowledge of P(n,t), J and $\tau(n)$, the nucleation barrier is calculated.

2 Supplemental Figures



Fig. 1 The glass transition temperature T_g of Cu₅₀Zr₅₀ film. (a) The film with the thickness of d = 3a. (b) Tg as a function of thickness



Fig. 2 The location distributions of crystal nucleus for $Cu_{50}Zr_{50}$ film with the thickness of d = 3a along the *z* direction.



Fig. 3 The liquidsolid equilibrium temperature of sphere-like nucleus versus the inverse of nucleus radius for CuZr. The solid lines are linear fits.



Fig. 4 Morphological evolution of crystal clusters in $Cu_{50}Zr_{50}$ liquid films. The red balls in (a) and (b) represent the cluster shapes for d = 4a at 800 K and the blue balls in (c) and (d) refer to the cluster for d = 5a at 800 K, respectively. The gray dots denote the liquid-like atoms.



Fig. 5 Stress along the *x*, *y*, and *z* directions for $Cu_{50}Zr_{50}$ film with different thickness (a = 4.22 Å, the lattice constant of CuZr compound), the open symbols denote the value of samples when the tensile stresses are applied.

References

- 1 P. R. Wolde et al., Faraday discussions, 1996, 104, 93–110.
- 2 Y. L , X. Zhang, M. Chen and J.-Z. Jiang, Phys. Chem. Chem. Phys., 2015, 17, 27167–27175.
- 3 J. Wedekind, R. Strey and D. Reguera, J. Chem. Phys., 2007, 126, 134103.
- 4 J. Wedekind and D. Reguera, J. Phys. Chem. B, 2008, 112, 11060–11063.